December 1994

# 54F/74F86 2-Input Exclusive-OR Gate

### **General Description**

This device contains four independent gates, each of which performs the logic exclusive-OR function.

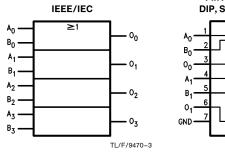
Commercial	Military	Package Number	Package Description		
74F86PC		N14A	14-Lead (0.300" Wide) Molded Dual-in-Line		
	54F86DM (Note 2)	J14A	14-Lead Ceramic Dual-in-Line		
74F86SC (Note 1)		M14A	14-Lead (0.150" Wide) Molded Small Outline, JEDEC		
74F86SJ (Note 1)		M14D	14-Lead (0.300" Wide) Molded Small Outline, EIAJ		
	54F86FM (Note 2)	W14B	14-Lead Cerpack		
	54F86LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C		

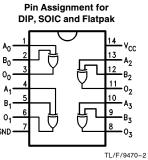
Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

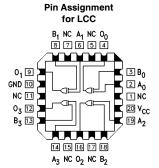
 $\textbf{Note 2:} \ \textbf{Military grade device with environmental and burn-in processing.} \ \textbf{Use suffix} = \textbf{DMQB, FMQB and LMQB.}$ 

### **Logic Symbol**

### **Connection Diagrams**







#### TL/F/9470-1

## **Unit Loading/Fan Out**

		54F/74F				
Pin Names	Description	U.L. HIGH/LOW	Input I <sub>IH</sub> /I <sub>IL</sub> Output I <sub>OH</sub> /I <sub>OL</sub>			
A <sub>n</sub> , B <sub>n</sub> O <sub>n</sub>	Inputs Outputs	1.0/1.0 50/33.3	20 μA/ – 0.6 mA – 1 mA/20 mA			

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### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

V<sub>CC</sub> Pin Potential to

 Ground Pin
 −0.5V to +7.0V

 Input Voltage (Note 2)
 −0.5V to +7.0V

 Input Current (Note 2)
 −30 mA to +5.0 mA

Voltage Applied to Output

in HIGH State (with  $V_{CC} = 0V$ )

 $\begin{array}{ll} \mbox{Standard Output} & -0.5\mbox{V to V}_{CC} \\ \mbox{TRI-STATE} \mbox{$^{\circ}$ Output} & -0.5\mbox{V to } +5.5\mbox{V} \end{array}$ 

Current Applied to Output

in LOW State (Max) twice the rated I<sub>OL</sub> (mA)

**Note 1:** Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

# Recommended Operating Conditions

Free Air Ambient Temperature

Supply Voltage

Military +4.5V to +5.5V Commercial +4.5V to +5.5V

### **DC Electrical Characteristics**

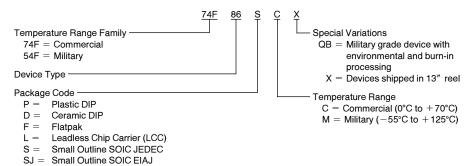
Symbol	Parameter		54F/74F			Units	V <sub>CC</sub>	Conditions	
Symbol			Min	Тур	Max	Oilles	VCC	Conditions	
V <sub>IH</sub>	Input HIGH Voltage		2.0			٧		Recognized as a HIGH Signal	
V <sub>IL</sub>	Input LOW Voltage				0.8	٧		Recognized as a LOW Signal	
V <sub>CD</sub>	Input Clamp Diode Vo	oltage			-1.2	V	Min	$I_{\text{IN}} = -18 \text{ mA}$	
V <sub>OH</sub>	Output HIGH Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub> 74F 5% V <sub>CC</sub>	2.5 2.5 2.7			V	Min	$I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$ $I_{OH} = -1 \text{ mA}$	
V <sub>OL</sub>	Output LOW Voltage	54F 10% V <sub>CC</sub> 74F 10% V <sub>CC</sub>			0.5 0.5	٧	Min	I <sub>OL</sub> = 20 mA I <sub>OL</sub> = 20 mA	
l <sub>IH</sub>	Input HIGH Current	54F 74F			20.0 5.0	μΑ	Max	V <sub>IN</sub> = 2.7V	
I <sub>BVI</sub>	Input HIGH Current Breakdown Test	54F 74F			100 7.0	μΑ	Max	V <sub>IN</sub> = 7.0V	
I <sub>CEX</sub>	Output HIGH Leakage Current	54F 74F			250 50	μΑ	Max	$V_{OUT} = V_{CC}$	
V <sub>ID</sub>	Input Leakage Test	74F	4.75			٧	0.0	$I_{\text{ID}} = 1.9  \mu\text{A}$ All other pins grounded	
I <sub>OD</sub>	Output Leakage Circuit Current	74F			3.75	μΑ	0.0	V <sub>IOD</sub> = 150 mV All other pins grounded	
I <sub>IL</sub>	Input LOW Current				-0.6	mA	Max	V <sub>IN</sub> = 0.5V	
los	Output Short-Circuit Current		-60		<b>-150</b>	mA	Max	V <sub>OUT</sub> = 0V	
Icch	Power Supply Current			12	18	mA	Max	V <sub>O</sub> = HIGH	
I <sub>CCL</sub>	Power Supply Current			18	28	mA	Max	$V_O = LOW$	

### **AC Electrical Characteristics**

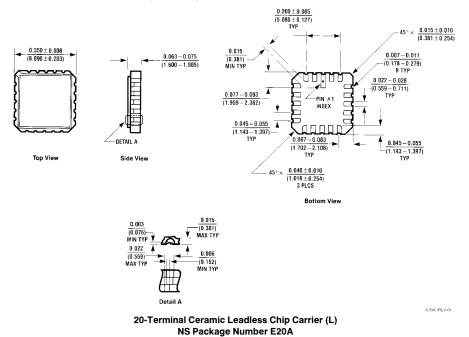
	Parameter	$ \begin{array}{c} {\it T_{A}} = +25^{\circ}{\it C} \\ {\it V_{CC}} = +5.0{\it V} \\ {\it C_{L}} = 50{\it pF} \end{array} $			$\begin{array}{c} 54F \\ T_{\text{A}}, V_{\text{CC}} = \text{Mil} \\ C_{\text{L}} = 50 \text{ pF} \end{array}$		74F  T <sub>A</sub> , V <sub>CC</sub> = Com C <sub>L</sub> = 50 pF		Units
Symbol									
		Min	Тур	Max	Min	Max	Min	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay A <sub>n</sub> , B <sub>n</sub> to O <sub>n</sub> (Other Input LOW)	3.0 3.0	4.0 4.2	5.5 5.5	2.5 3.0	7.0 7.0	3.0 3.0	6.5 6.5	ns
t <sub>PLH</sub>	Propagation Delay  A <sub>n</sub> , B <sub>n</sub> to O <sub>n</sub> (Other Input HIGH)	3.5 3.0	5.3 4.7	7.0 6.5	3.5 3.0	8.5 8.0	3.5 3.0	8.0 7.5	ns

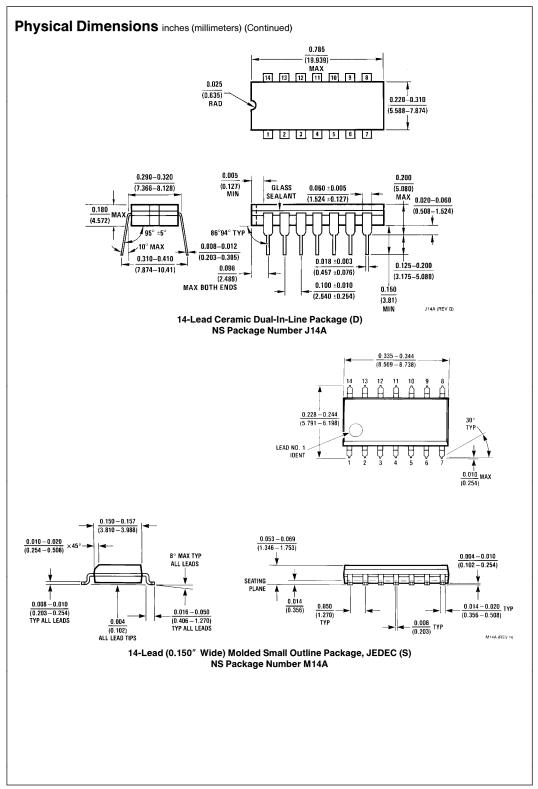
### **Ordering Information**

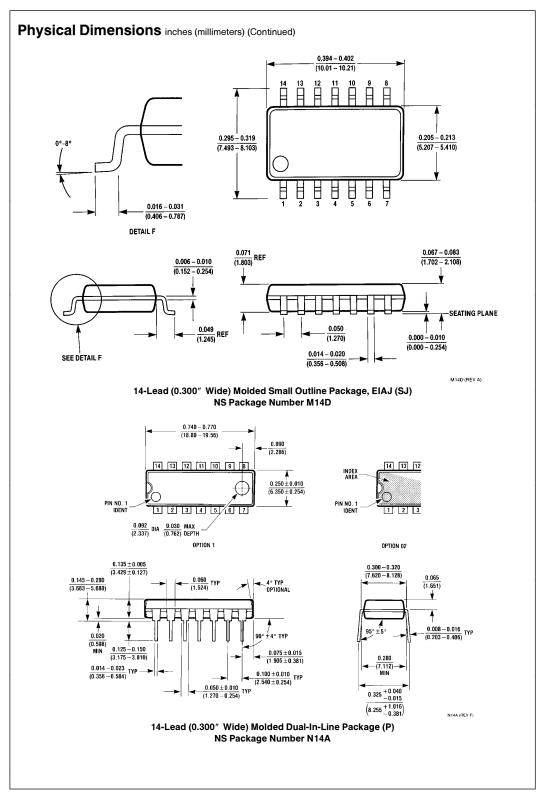
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



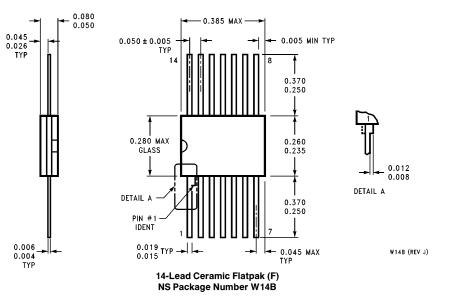
## Physical Dimensions inches (millimeters)







### Physical Dimensions inches (millimeters) (Continued)



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